

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

### SS22 THRU SS26

## SURFACE MOUNT SCHOTTKY **BARRIER RECTIFIER**

**TECHNICAL SPECIFICATION** 

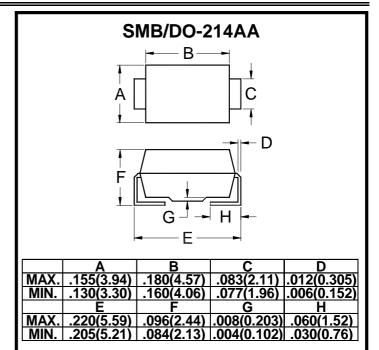
**VOLTAGE: 20 TO 60V CURRENT: 2.0A** 

#### **FEATURES**

- · Ideal for surface mount pick and place application
- Low profile package
- Low power loss, high efficiency
- High current capability, low V<sub>F</sub>
- High surge capability
- High temperature soldering guaranteed: 260°C/10sec/at terminal

#### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: Molded with UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Color band denotes cathode



Dimensions in inches and (millimeters)

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

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RATINGS	SYMBOL	SS22	SS23	SS24	SS25	SS26	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	20	30	40	50	60	V
Maximum RMS Voltage	$V_{RMS}$	14	21	28	35	42	V
Maximum DC Blocking Voltage	$V_{DC}$	20	30	40	50	60	V
Maximum Average Forward Rectified Curren $(T_L=100^{\circ}C)$	t I <sub>F(AV)</sub>	2.0				А	
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	50					А
Maximum Instantaneous Forward Voltage (at rated forward current)	$V_{F}$		0.5		0	.7	V
Maximum DC Reverse Current T <sub>a</sub> =25°	C ,	0.5					mΑ
(at rated DC blocking voltage) T <sub>a</sub> =100°	C I <sub>R</sub>	10.0					mA
Typical Junction Capacitance (Note	1) C <sub>J</sub>	200					pF
Typical Thermal Resistance (Note:	$R_{\theta}(ja)$	25					°C/W
Storage and Operation Junction Temperature	T <sub>STG</sub> ,T <sub>J</sub>	-65 to +150					°C
Note:							

- 1.Measured at 1.0 MHz and applied voltage of 4.0V<sub>dc</sub>
- 2. Thermal resistance from junction to terminal mounted on 5×5mm copper pad area